P26B10SL

Power MOSFETs 100V, 26A, N-channel

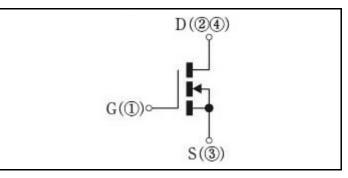
Feature

- N-channel
- SMD
- Low Ron
- 4.5V Gate Drive
- Low Capacitance
- Pb free terminal
- · RoHS:Yes

OUTLINE



Equivalent circuit



Absolute Maximum Ratings (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings	Unit
Storage temperrature	Tstg		-55 to 150	°C
Channel tempertature	Tch		-55 to 150	°C
Drain-source voltage	V _{DSS}		100	V
Gate-source voltage	V _{GSS}		±20	V
Continuous drain current(DC)	I _D		26	А
Continuous drain current(Peak)	I _{DP}	Pulse width 10µs, duty=1/100	78	А
Total power dissipation	P _T		44	W
Single avalanche current	I _{AS}	Starting Tch=25°C Tch≦150°C	19	А
Single avalanche energy	E _{AS}	Starting Tch=25°C Tch≦150°C	40	mJ

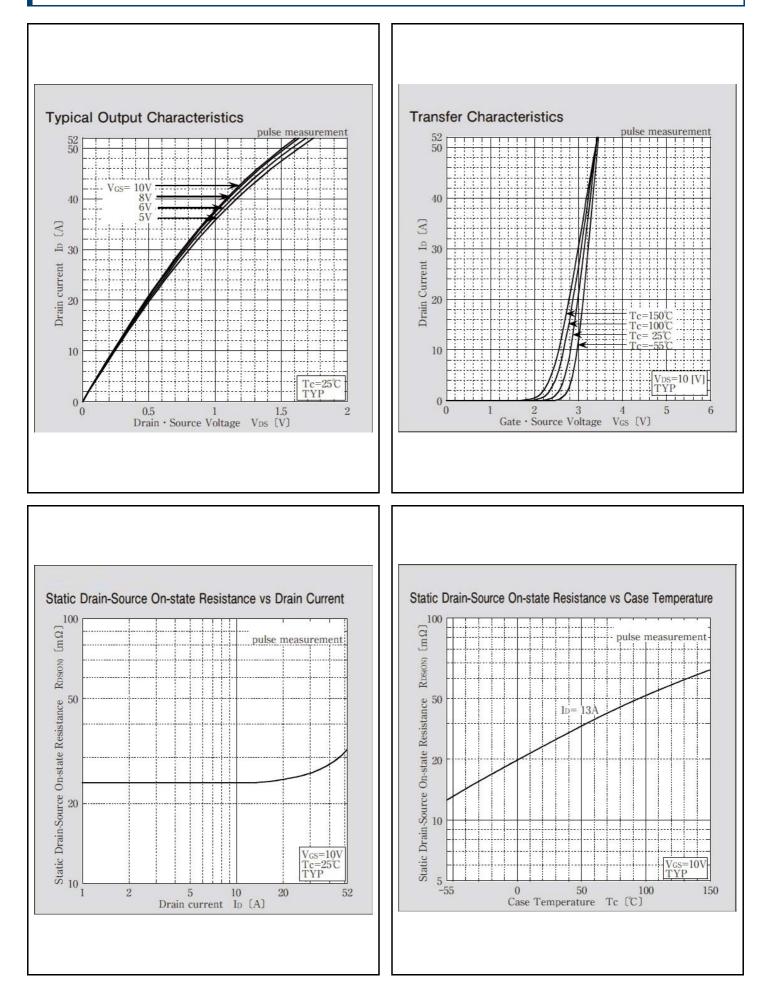
* : See the original Specifications

Electrical Characteristics	(unless otherwise specified : Tc=25°C)

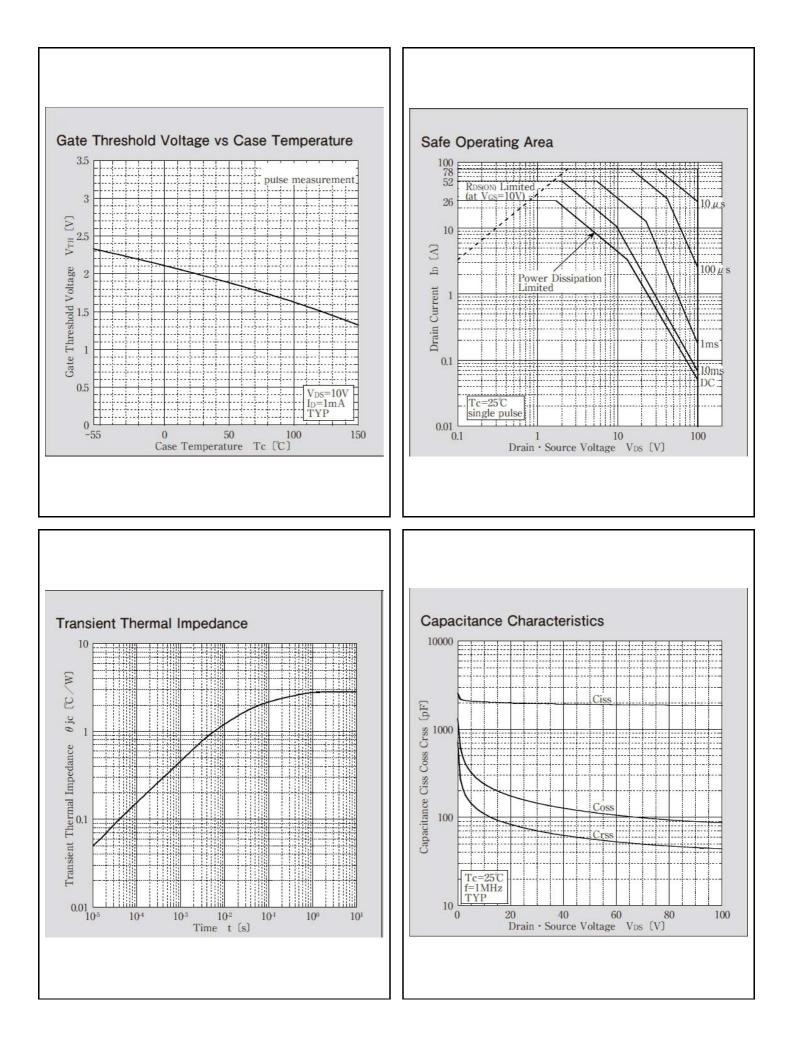
	Symbol	Conditions		Ratings		
Item			MIN	ТҮР	MAX	Unit
Drain-Source breakdown voltage	V _{(BR)DSS}	ID=1mA, VGS=0V	100			V
Zero gate voltage drain current	I _{DSS}	VDS=100V, VGS=0V			1	μA
Gate-source leakage current	I _{GSS}	VGS=±20V, VDS=0V			±0.1	μA
Forward transconductance	g _{fs}	ID=13A, VDS=10V	8	16		S
Static drain-source on-state resistance	R _{DS(ON)}	ID=13A, VGS=10V		0.024	0.03	Ω
Static drain-source on-state resistance	R _{DS(ON)}	ID=13A, VGS=4.5V		0.026	0.035	Ω
Gate threshold voltage	Vth	ID=1mA, VDS=10V	1.5	2	2.5	V
Source-drain diode forward voltage	V _{SD}	IS=26A, VGS=0V			1.5	V
Thermal resistance	Rth(j-c)	Junction to case, with heatsink st			2.84	°C/W
Total gate charge	Qg	VDD=80V, VGS=10V, ID=26A		43		nC
Gate to source charge	Qgs	VDD=80V, VGS=10V, ID=26A		9		nC
Gate to drain charge	Qgd	VDD=80V, VGS=10V, ID=26A		12		nC
Input capacitance	Ciss	VDS=25V, VGS=0V, f=1MHz		1975		pF
Reverce transfer capacitnce	Crss	VDS=25V, VGS=0V, f=1MHz		76		pF
Output capacitance	Coss	VDS=25V, VGS=0V, f=1MHz		158		pF
Turn-on delay time	td(on)	ID=13A, RL=3.85Ω, VDD=50V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		6		ns
Rise time	tr	ID=13A, RL=3.85Ω, VDD=50V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		10		ns
Turn-off delay time	td(off)	ID=13A, RL=3.85Ω, VDD=50V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		30		ns
Fall time	tf	ID=13A, RL=3.85Ω, VDD=50V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		17		ns
Diode reverse recovery time	trr	IF=26A, VGS=0V, di/dt=100A/µs		53		ns
Diode reverse recovery charge	Qrr	IF=26A, VGS=0V, di/dt=100A/µs		100		nC

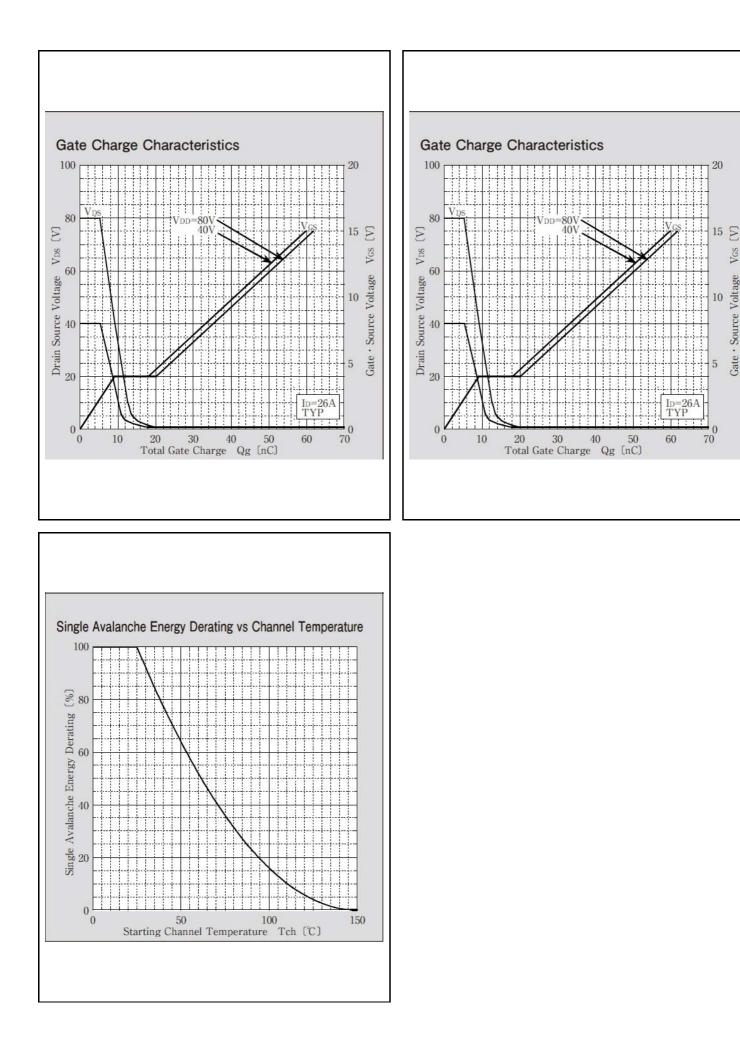
* : See the original Specifications

CHARACTERISTIC DIAGRAMS



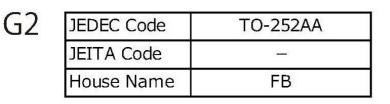
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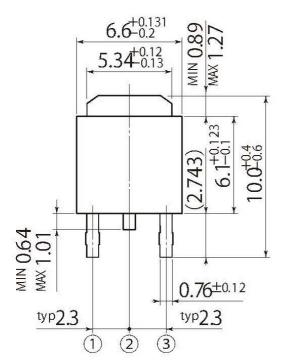


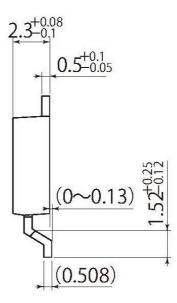


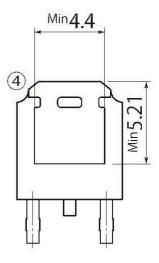
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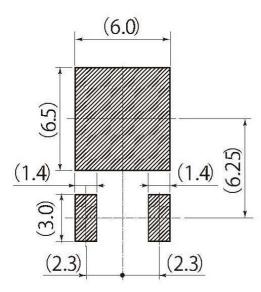
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Referential Soldering Pad

• Optimize soldering pad to the board design and soldering condition.

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